

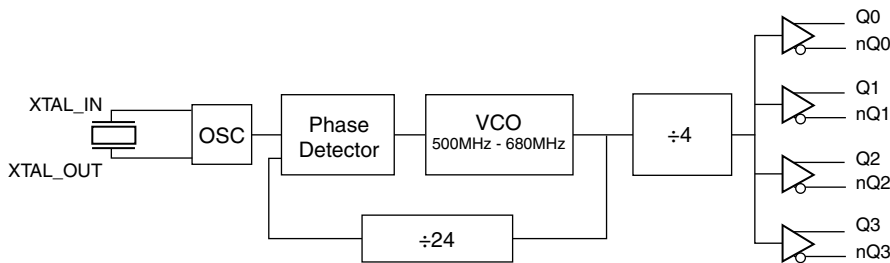
### General Description

The 844244I-04 is a Serial ATA (SATA)/Serial Attached SCSI (SAS) Clock Generator. For SATA/SAS applications, a 25MHz crystal is used to produce 150MHz. The 844244I-04 has excellent <1ps phase jitter performance, over the 12kHz - 20MHz integration range. The 844244I-04-04 is packaged in a small 16-pin TSSOP, making it ideal for use in systems with limited board space.

### Features

- Four differential LVDS output pairs
- Crystal oscillator interface, 18pF parallel resonant crystal (20.833MHz – 28.3MHz)
- Output frequency range: 125MHz – 170MHz
- VCO range: 500MHz – 680MHz
- RMS phase jitter at 150MHz, using a 25MHz crystal (12kHz – 20MHz): 0.9ps (typical) @ 3.3V
- Full 3.3V or 2.5V output supply modes
- -40°C to 85°C ambient operating temperature
- Available in lead-free (RoHS 6) package

### Block Diagram



### Pin Assignment

Q2	1	16	Q0
nQ2	2	15	nQ0
V <sub>DD</sub>	3	14	V <sub>DD</sub>
Q3	4	13	Q1
nQ3	5	12	nQ1
GND	6	11	GND
V <sub>DDA</sub>	7	10	XTAL_IN
V <sub>DD</sub>	8	9	XTAL_OUT

**844244I-04**

**16 Lead TSSOP**

**4.4mm x 5.0mm package body**

**Table 1. Pin Descriptions**

Number	Name	Type	Description
1, 2	Q2, nQ2	Output	Differential clock output pair. LVDS interface levels.
3, 8, 14	V <sub>DD</sub>	Power	Core supply pins.
4, 5	Q3, nQ3	Output	Differential clock output pair. LVDS interface levels.
6, 11	GND	Power	Power supply ground.
7	V <sub>DDA</sub>	Power	Analog supply pin.
9, 10	XTAL_OUT, XTAL_IN	Input	Crystal oscillator interface. XTAL_IN is the input, XTAL_OUT is the output.
12, 13	nQ1, Q1	Output	Differential clock output pair. LVDS interface levels.
15, 16	nQ0, Q0	Output	Differential clock output pair. LVDS interface levels.

## Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V <sub>DD</sub>	4.6V
Inputs, V <sub>I</sub> XTAL_IN Other Inputs	0V to V <sub>DD</sub> -0.5V to V <sub>DD</sub> + 0.5V
Outputs, I <sub>O</sub> Continuous Current Surge Current	10mA 15mA
Package Thermal Impedance, $\theta_{JA}$	92.4°C/W (0 mps)
Storage Temperature, T <sub>STG</sub>	-65°C to 150°C

## DC Electrical Characteristics

**Table 2A. Power Supply DC Characteristics, V<sub>DD</sub> = 3.3V ± 5%, T<sub>A</sub> = -40°C to 85°C**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V <sub>DD</sub>	Core Supply Voltage		3.135	3.3	3.465	V
V <sub>DDA</sub>	Analog Supply Voltage		V <sub>DD</sub> - 0.10	3.3	V <sub>DD</sub>	V
I <sub>DD</sub>	Power Supply Current				121	mA
I <sub>DDA</sub>	Analog Supply Current				10	mA

**Table 2B. Power Supply DC Characteristics,  $V_{DD} = 2.5V \pm 5\%$ ,  $T_A = -40^\circ C$  to  $85^\circ C$** 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{DD}$	Core Supply Voltage		2.375	2.5	2.625	V
$V_{DDA}$	Analog Supply Voltage		$V_{DD} - 0.10$	2.5	$V_{DD}$	V
$I_{DD}$	Power Supply Current				115	mA
$I_{DDA}$	Analog Supply Current				10	mA

**Table 2C. LVCMOS/LVTTL DC Characteristics,  $V_{DD} = 3.3V \pm 5\%$  or  $2.5V \pm 5\%$ ,  $T_A = -40^\circ C$  to  $85^\circ C$** 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{IH}$	Input High Voltage	$V_{DD} = 3.3V \pm 5\%$	2		$V_{DD} + 0.3$	V
		$V_{DD} = 2.5V \pm 5\%$	1.7		$V_{DD} + 0.3$	V
$V_{IL}$	Input Low Voltage	$V_{DD} = 3.3V \pm 5\%$	-0.3		0.8	V
		$V_{DD} = 2.5V \pm 5\%$	-0.3		0.7	V

**Table 2D. LVDS DC Characteristics,  $V_{DD} = 3.3V \pm 5\%$ ,  $T_A = -40^\circ C$  to  $85^\circ C$** 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{OD}$	Differential Output Voltage		240		460	mV
$\Delta V_{OD}$	$V_{OD}$ Magnitude Change				50	mV
$V_{OS}$	Offset Voltage		1.17		1.52	V
$\Delta V_{OS}$	$V_{OS}$ Magnitude Change				50	mV

**Table 2E. LVDS DC Characteristics,  $V_{DD} = 2.5V \pm 5\%$ ,  $T_A = -40^\circ C$  to  $85^\circ C$** 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{OD}$	Differential Output Voltage		240		460	mV
$\Delta V_{OD}$	$V_{OD}$ Magnitude Change				50	mV
$V_{OS}$	Offset Voltage		1.10		1.40	V
$\Delta V_{OS}$	$V_{OS}$ Magnitude Change				50	mV

**Table 3. Crystal Characteristics**

Parameter	Test Conditions	Minimum	Typical	Maximum	Units
Mode of Oscillation		Fundamental			
Frequency		20.833	25	28.3	MHz
Equivalent Series Resistance (ESR)				50	$\Omega$
Shunt Capacitance				7	pF

## AC Electrical Characteristics

**Table 4A. AC Characteristics,  $V_{DD} = 3.3V \pm 5\%$ ,  $T_A = -40^\circ C$  to  $85^\circ$**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$f_{OUT}$	Output Frequency		125	150	170	MHz
$f_{jit}(\emptyset)$	RMS Phase Jitter, Random; NOTE 1	150MHz, Integration Range: 12kHz – 20MHz		0.9		ps
$t_{sk(o)}$	Output Skew; NOTE 2, 3				65	ps
$t_R / t_F$	Output Rise/Fall Time	20% to 80%	250		650	ps
odc	Output Duty Cycle		48		52	%

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE: Characterized using a 25MHz crystal,  $f_{OUT}$  @ 150MHz.

NOTE 1: Refer to Phase Noise Plots.

NOTE 2: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 3: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at the output differential cross points.

**Table 4B. AC Characteristics,  $V_{DD} = 2.5V \pm 5\%$ ,  $T_A = -40^\circ C$  to  $85^\circ$**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$f_{OUT}$	Output Frequency		125	150	170	MHz
$f_{jit}(\emptyset)$	RMS Phase Jitter, Random; NOTE 1	150MHz, Integration Range: 12kHz – 20MHz		1.1		ps
$t_{sk(o)}$	Output Skew; NOTE 2, 3				65	ps
$t_R / t_F$	Output Rise/Fall Time	20% to 80%	200		650	ps
odc	Output Duty Cycle		48		52	%

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

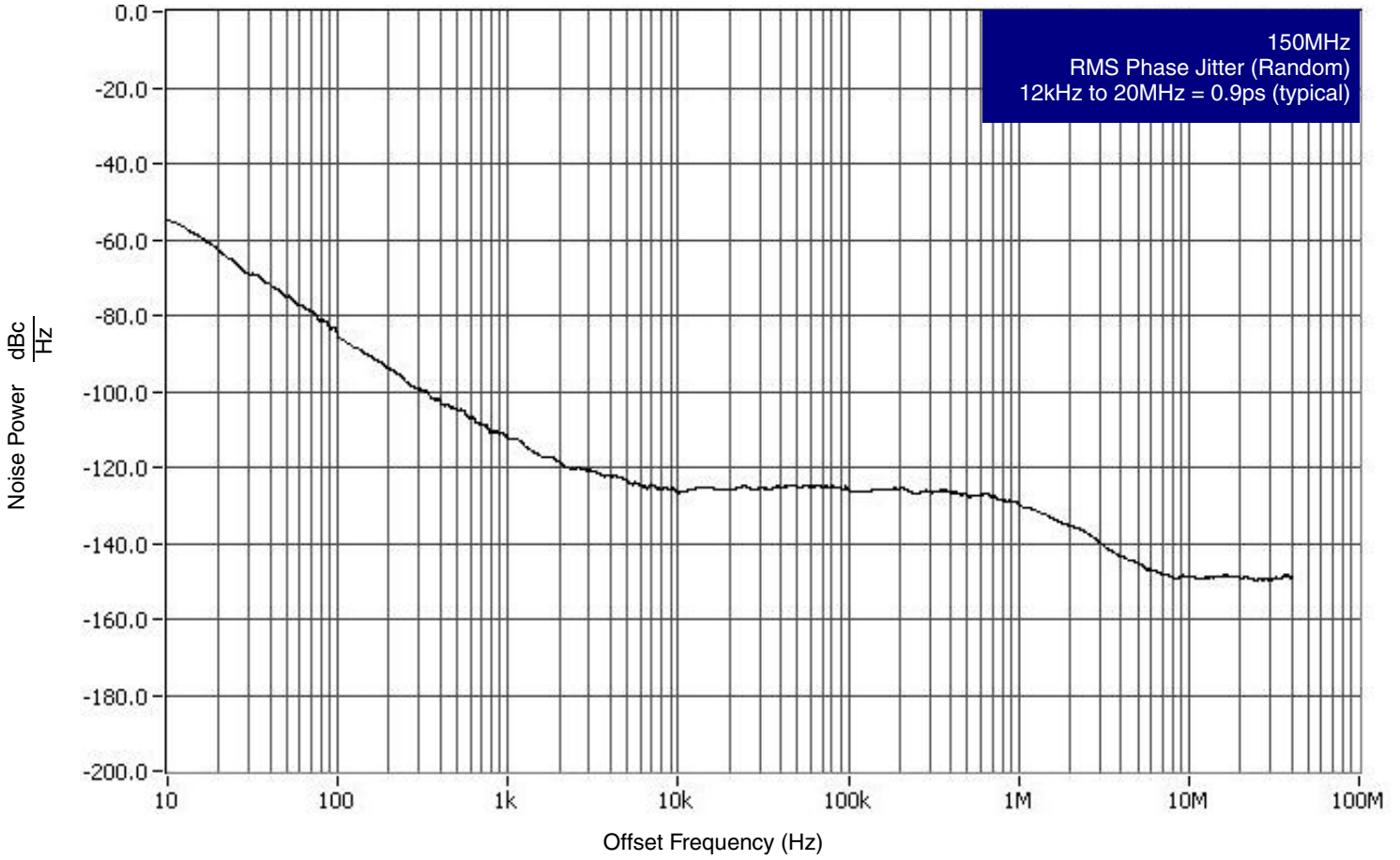
NOTE: Characterized using a 25MHz crystal,  $f_{OUT}$  @ 150MHz.

NOTE 1: Refer to Phase Noise Plots.

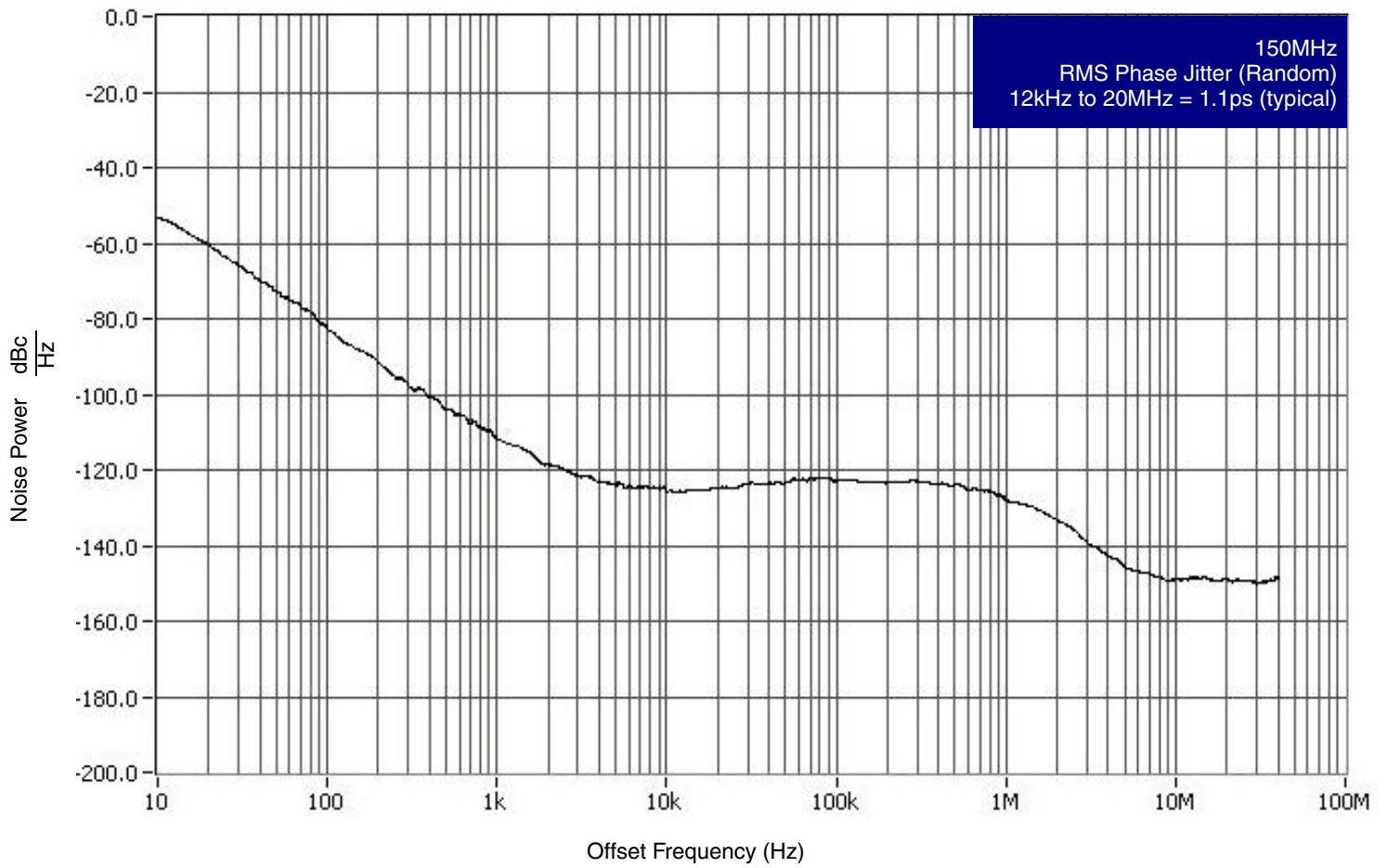
NOTE 2: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 3: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at the output differential cross points.

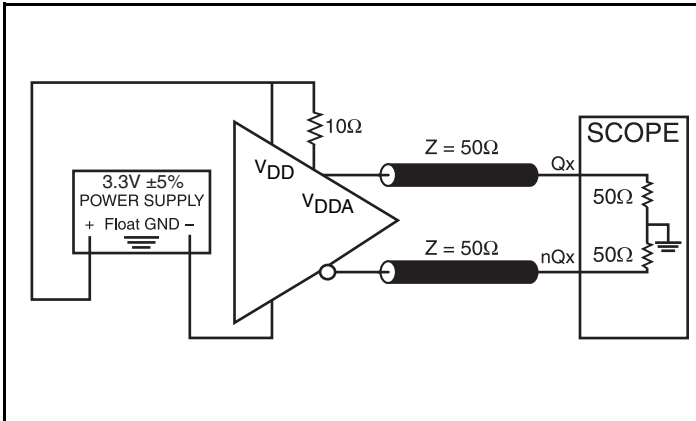
### Typical Phase Noise at 150MHz (3.3V)



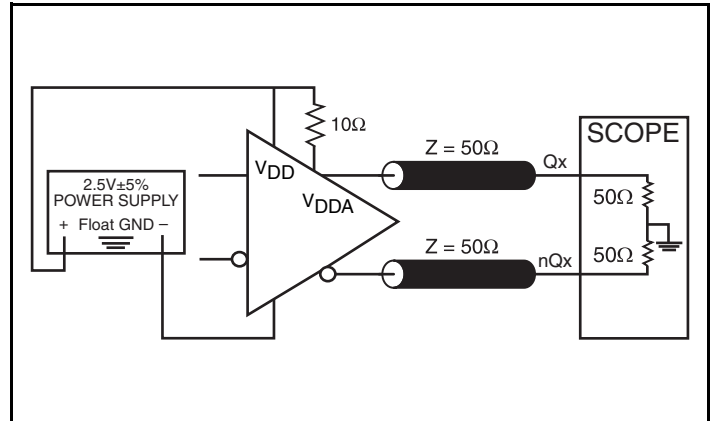
## Typical Phase Noise at 150MHz (2.5V)



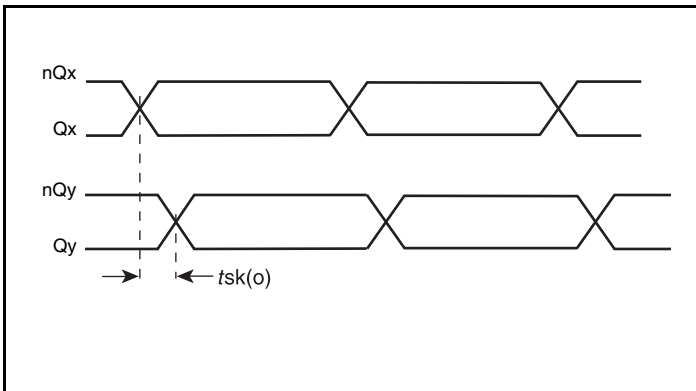
### Parameter Measurement Information



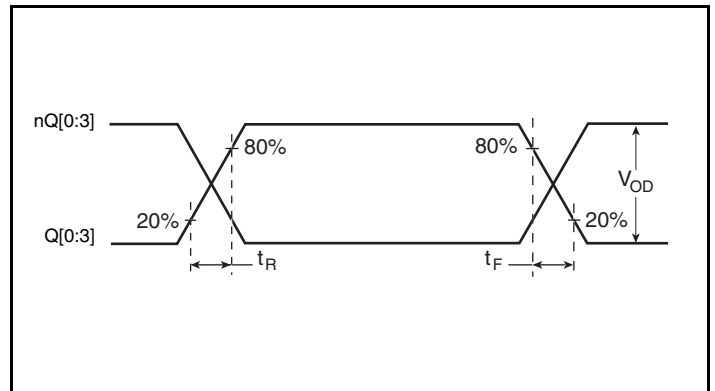
3.3V LVDS Output Load AC Test Circuit



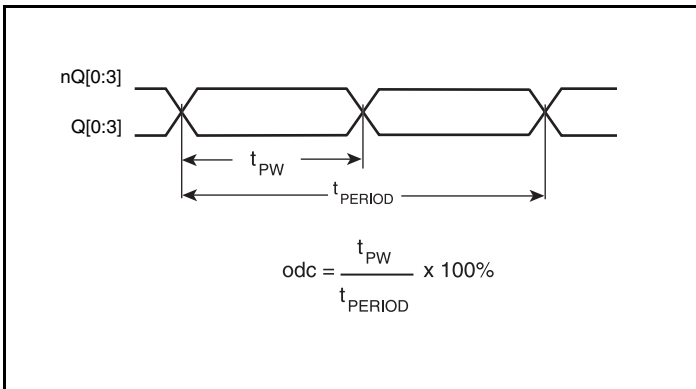
2.5V LVDS Output Load AC Test Circuit



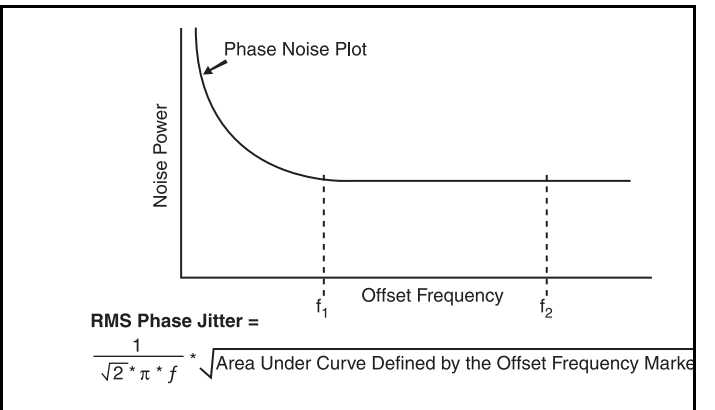
Output Skew



Output Rise/Fall Time

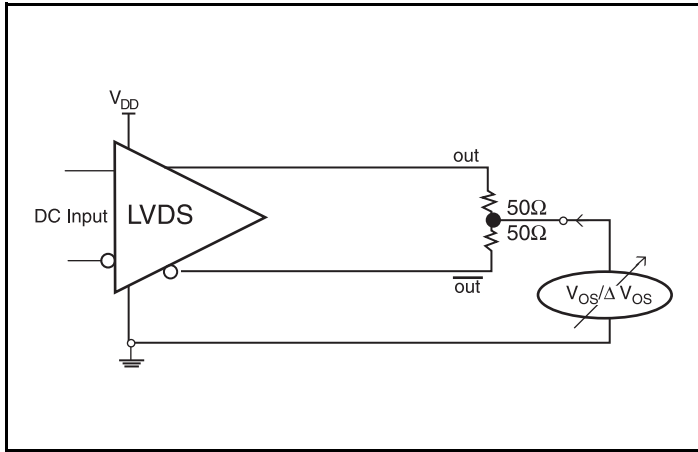


Output Duty Cycle/Pulse Width/Period

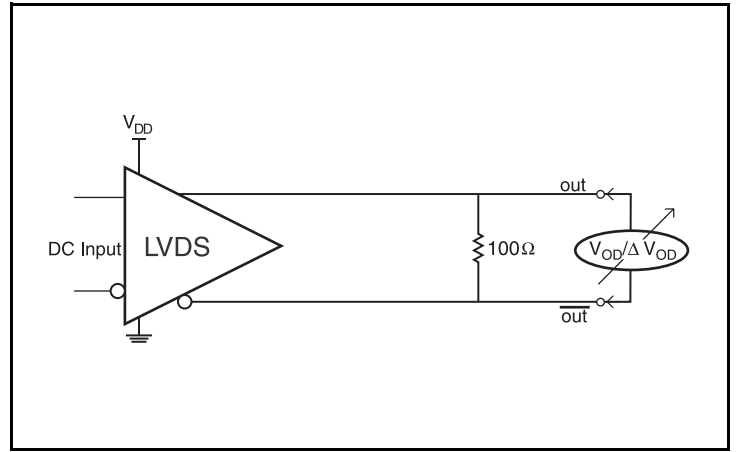


RMS Phase Jitter

## Parameter Measurement Information, continued



Offset Voltage Setup

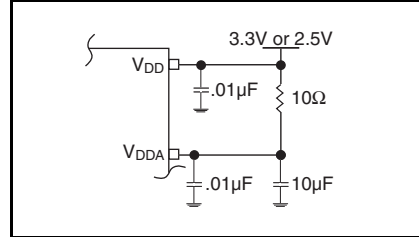


Differential Output Voltage Setup

## Application Information

### Power Supply Filtering Technique

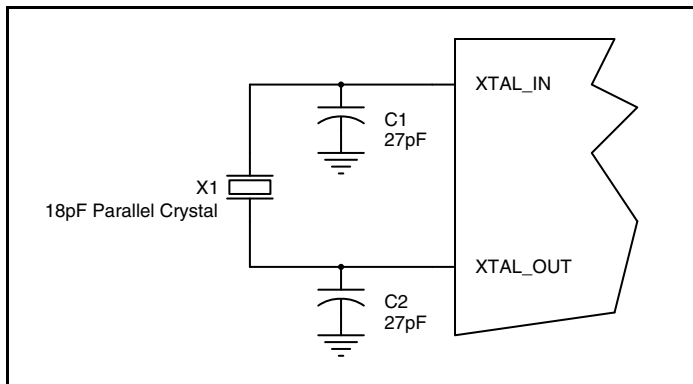
As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. The 844244I-04 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL.  $V_{DD}$  and  $V_{DDA}$  should be individually connected to the power supply plane through vias, and  $0.01\mu\text{F}$  bypass capacitors should be used for each pin. *Figure 1* illustrates this for a generic  $V_{DD}$  pin and also shows that  $V_{DDA}$  requires that an additional  $10\Omega$  resistor along with a  $10\mu\text{F}$  bypass capacitor be connected to the  $V_{DDA}$  pin.



**Figure 1. Power Supply Filtering**

### Crystal Input Interface

The 844244I-04 has been characterized with  $18\text{pF}$  parallel resonant crystals. The capacitor values,  $C1$  and  $C2$ , shown in *Figure 2* below were determined using a  $25\text{MHz}$ ,  $18\text{pF}$  parallel resonant crystal and were chosen to minimize the ppm error. The optimum  $C1$  and  $C2$  values can be slightly adjusted for different board layouts.

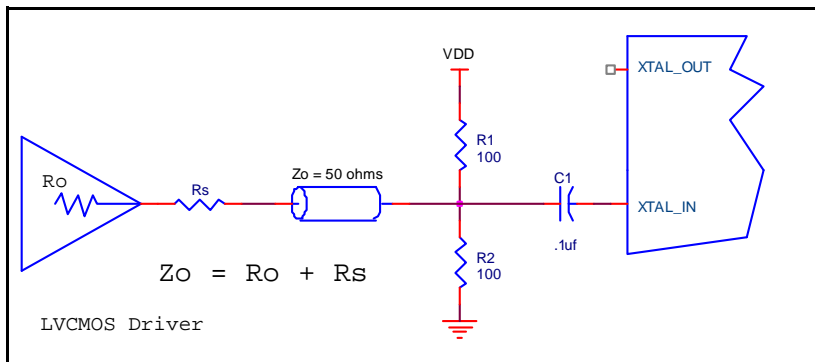


**Figure 2. Crystal Input Interface**

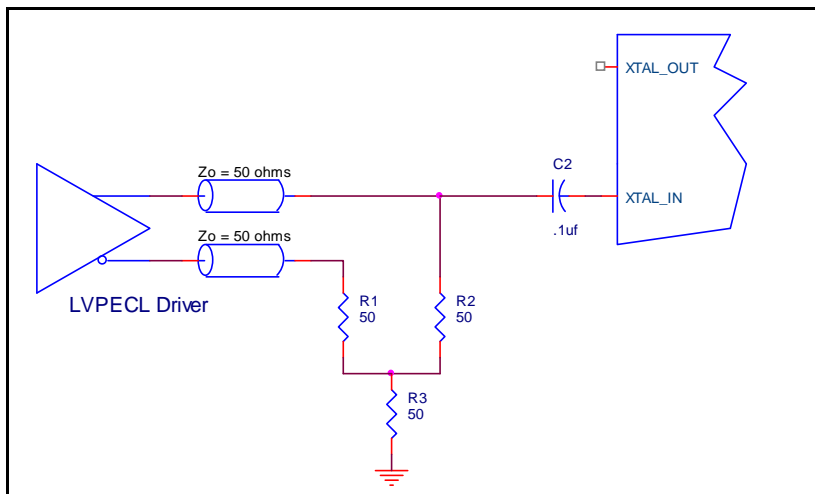
## Overdriving the XTAL Interface

The XTAL\_IN input can be overdriven by an LVCMOS driver or by one side of a differential driver through an AC coupling capacitor. The XTAL\_OUT pin can be left floating. The amplitude of the input signal should be between 500mV and 1.8V and the slew rate should not be less than 0.2V/ns. For 3.3V LVCMOS inputs, the amplitude must be reduced from full swing to at least half the swing in order to prevent signal interference with the power rail and to reduce internal noise. *Figure 3A* shows an example of the interface diagram for a high speed 3.3V LVCMOS driver. This configuration requires that the sum of the output impedance of the driver ( $R_o$ ) and the series resistance ( $R_s$ ) equals the transmission line impedance. In addition, matched termination at the crystal input will attenuate the signal in half. This

can be done in one of two ways. First,  $R_1$  and  $R_2$  in parallel should equal the transmission line impedance. For most 50Ω applications,  $R_1$  and  $R_2$  can be 100Ω. This can also be accomplished by removing  $R_1$  and changing  $R_2$  to 50Ω. The values of the resistors can be increased to reduce the loading for a slower and weaker LVCMOS driver. *Figure 3B* shows an example of the interface diagram for an LVPECL driver. This is a standard LVPECL termination with one side of the driver feeding the XTAL\_IN input. It is recommended that all components in the schematics be placed in the layout. Though some components might not be used, they can be utilized for debugging purposes. The datasheet specifications are characterized and guaranteed by using a quartz crystal as the input.



**Figure 3A. General Diagram for LVCMOS Driver to XTAL Input Interface**



**Figure 3B. General Diagram for LVPECL Driver to XTAL Input Interface**

## Recommendations for Unused Output Pins

### Outputs:

#### LVDS Outputs

All unused LVDS output pairs can be either left floating or terminated with  $100\Omega$  across. If they are left floating, we recommend that there is no trace attached.

#### LVDS Driver Termination

For a general LVDS interface, the recommended value for the termination impedance ( $Z_T$ ) is between  $90\Omega$  and  $132\Omega$ . The actual value should be selected to match the differential impedance ( $Z_0$ ) of your transmission line. A typical point-to-point LVDS design uses a  $100\Omega$  parallel resistor at the receiver and a  $100\Omega$  differential transmission-line environment. In order to avoid any transmission-line reflection issues, the components should be surface mounted and must be placed as close to the receiver as possible. IDT offers a full line of LVDS compliant devices with two types of output structures: current source and voltage source. The standard termination schematic as shown in Figure 4A can be used

with either type of output structure. Figure 4B, which can also be used with both output types, is an optional termination with center tap capacitance to help filter common mode noise. The capacitor value should be approximately  $50\text{pF}$ . If using a non-standard termination, it is recommended to contact IDT and confirm if the output structure is current source or voltage source type. In addition, since these outputs are LVDS compatible, the input receiver's amplitude and common-mode input range should be verified for compatibility with the output.

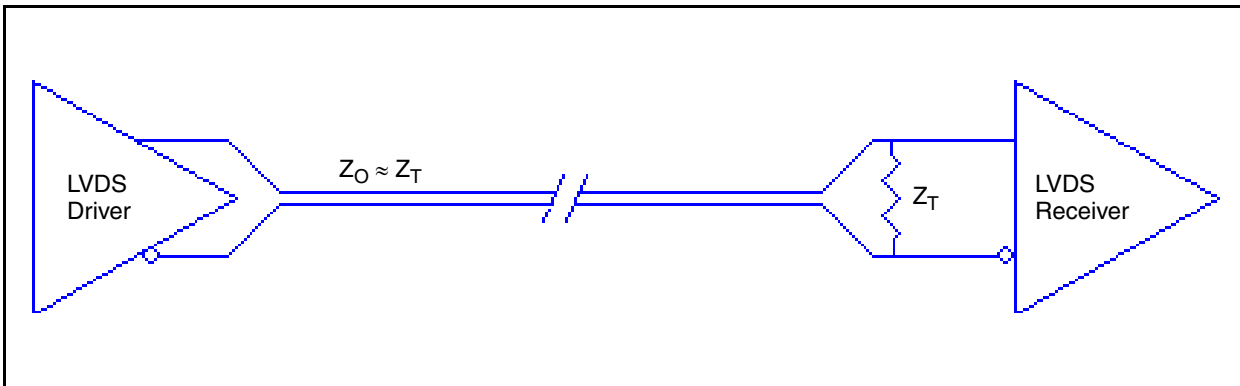


Figure 4A. Standard LVDS Termination

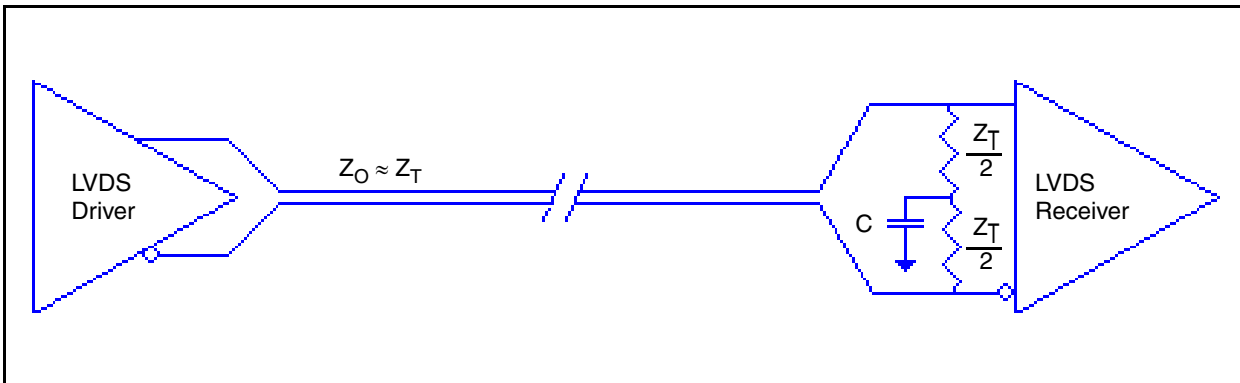


Figure 4B. Optional LVDS Termination

### Application Schematic Example

Figure 5 shows an example of 844244I-04 application schematic. In this example, the device is operated at  $V_{DD} = 3.3V$ . The decoupling capacitor should be located as close as possible to the power pin. The 18pF parallel resonant 25MHz crystal is used. The  $C1 = 27pF$

and  $C2 = 27pF$  are recommended for frequency accuracy. For different board layouts, the  $C1$  and  $C2$  may be slightly adjusted for optimizing frequency accuracy. For the LVDS output drivers, place a  $100\Omega$  resistor as close to the receiver as possible.

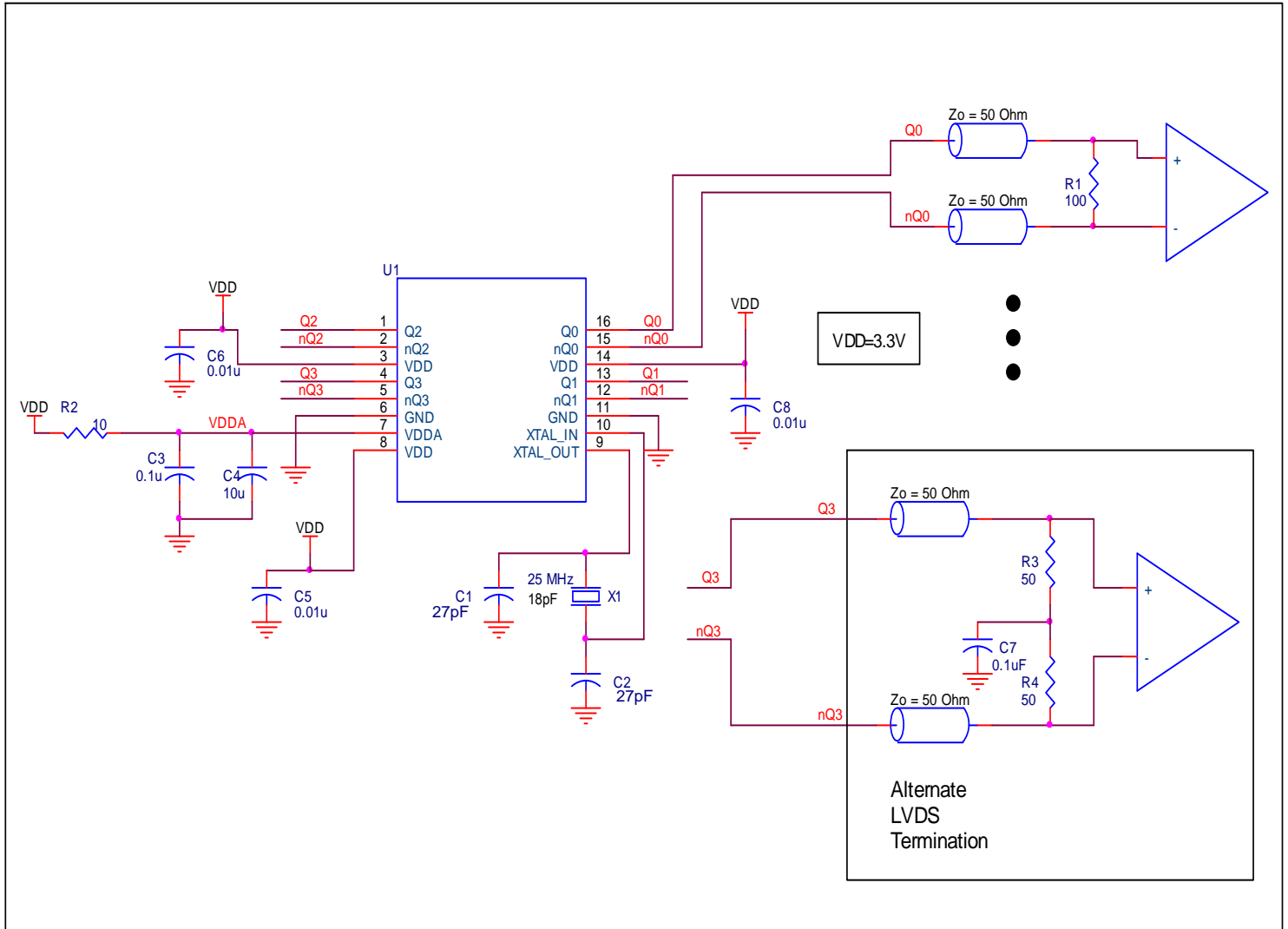


Figure 5. 844244I-04 Application Schematic

## Power Considerations

This section provides information on power dissipation and junction temperature for the 844244I-04. Equations and example calculations are also provided.

### 1. Power Dissipation.

The total power dissipation for the 844244I-04 is the sum of the core power plus the analog power plus the power dissipation in the load(s). The following is the power dissipation for  $V_{DD} = 3.3V + 5\% = 3.465V$ , which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipation in the load.

- Power (core)<sub>MAX</sub> =  $V_{DD\_MAX} * (I_{DD\_MAX} + I_{DDA\_MAX}) = 3.465V * (121mA + 10mA) = 453.9mW$

### 2. Junction Temperature.

Junction temperature,  $T_j$ , is the temperature at the junction of the bond wire and bond pad, and directly affects the reliability of the device. The maximum recommended junction temperature is 125°C. Limiting the internal transistor junction temperature,  $T_j$ , to 125°C ensures that the bond wire and bond pad temperature remains below 125°C.

The equation for  $T_j$  is as follows:  $T_j = \theta_{JA} * Pd\_total + T_A$

$T_j$  = Junction Temperature

$\theta_{JA}$  = Junction-to-Ambient Thermal Resistance

$Pd\_total$  = Total Device Power Dissipation (example calculation is in section 1 above)

$T_A$  = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance  $\theta_{JA}$  must be used. Assuming a moderate air flow of 1 meter per second and a multi-layer board, the appropriate value is 88°C/W per Table 5 below.

Therefore,  $T_j$  for an ambient temperature of 85°C with all outputs switching is:

$$85^\circ\text{C} + 0.4539W * 88^\circ\text{C/W} = 124.9^\circ\text{C}. \text{ This is below the limit of } 125^\circ\text{C}.$$

This calculation is only an example.  $T_j$  will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (multi-layer).

**Table 5. Thermal Resistance  $\theta_{JA}$  for 16 Lead TSSOP, Forced Convection**

Meters per Second	$\theta_{JA}$ by Velocity		
	0	1	2.5
Multi-Layer PCB, JEDEC Standard Test Boards	92.4°C/W	88.0°C/W	85.9°C/W

## Reliability Information

Table 6.  $\theta_{JA}$  vs. Air Flow Table for a 16 Lead TSSOP

$\theta_{JA}$ vs. Air Flow			
Meters per Second	0	1	2.5
Multi-Layer PCB, JEDEC Standard Test Boards	92.4°C/W	88.0°C/W	85.9°C/W

## Transistor Count

The transistor count for 844244I-04 is: 1990

## Package Outline and Package Dimensions

Package Outline - G Suffix for 8 Lead TSSOP

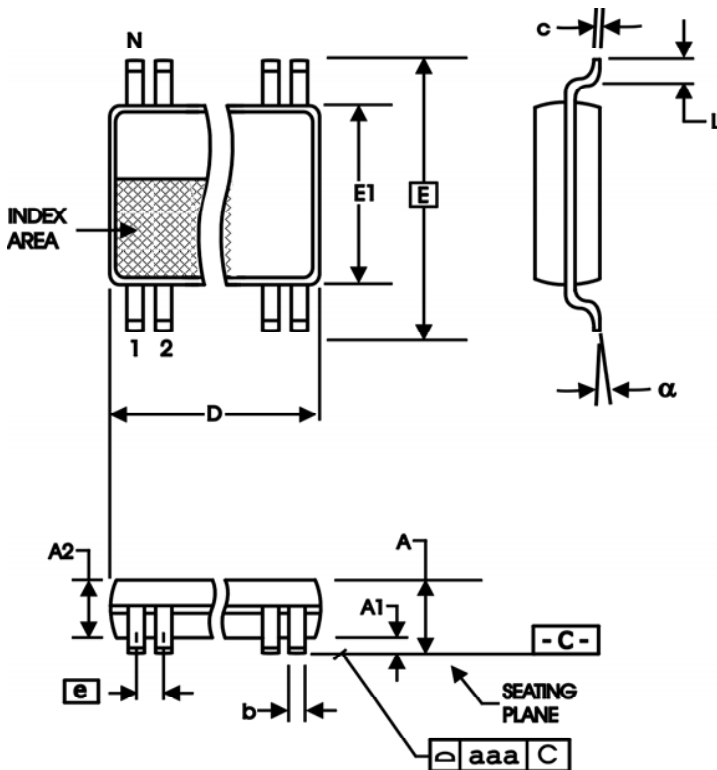


Table 7. Package Dimensions

All Dimensions in Millimeters		
Symbol	Minimum	Maximum
N	16	
A		1.20
A1	0.05	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	4.90	5.10
E	6.40 Basic	
E1	4.30	4.50
e	0.65 Basic	
L	0.45	0.75
$\alpha$	0°	8°
aaa		0.10

Reference Document: JEDEC Publication 95, MO-153

## Ordering Information

Table 8. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
844244AGI-04LF	244AI04L	"Lead-Free" 16 Lead TSSOP	Tube	-40°C to 85°C
844244AGI-04LFT	244AI04L	"Lead-Free" 16 Lead TSSOP	Tape & Reel	-40°C to 85°C

## Revision History Sheet

Rev	Table	Page	Description of Change	Date
B	T8		Updated header/footer through the datasheet.	10/15/15
		1	Deleted IDT prefix from part number.	
		10	Features Section - deleted leaded information in the last bullet.	
		11	Updated <i>Overdriving the XTAL Interface</i> application note.	
		15	Updated <i>LVDS Driver Termination</i> application note.	
			Ordering Information table - deleted leaded parts rows.	



**Corporate Headquarters**  
6024 Silver Creek Valley Road  
San Jose, CA 95138 USA

**Sales**  
1-800-345-7015 or 408-284-8200  
Fax: 408-284-2775  
www.IDT.com

**Tech Support**  
email: [clocks@idt.com](mailto:clocks@idt.com)

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TOYOSU FORESIA, 3-2-24 Toyosu,  
Koto-ku, Tokyo 135-0061, Japan  
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